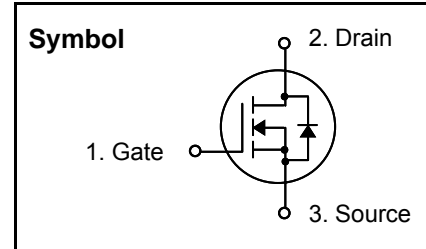


Logic N-Channel MOSFET

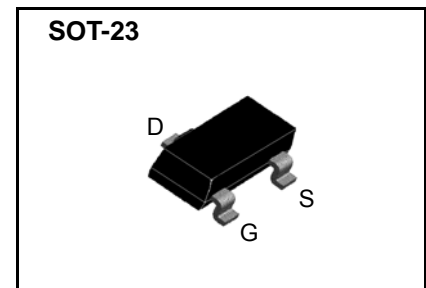
Features

- $R_{DS(on)}$ (Max 7.5 Ω)@ $V_{GS}=10V$
 $R_{DS(on)}$ (Max 7.5 Ω)@ $V_{GS}=4.5V$
- Gate Charge (Typical 0.5nC)
- Maximum Junction Temperature Range (150°C)



General Description

This Power MOSFET is produced using planar DMOS technology. And this Power MOSFET is well suited for Battery switch, Load switch, Motor controller and other small signal switches.



Absolute Maximum Ratings

Symbol	Parameter	Value	Units
V_{DSS}	Drain to Source Voltage	60	V
I_D	Continuous Drain Current(@ $T_A = 25^\circ C$)	115	mA
I_{DM}	Drain Current Pulsed (Note 1)	800	mA
V_{GS}	Gate to Source Voltage	± 20	V
P_D	Total Power Dissipation Single Operation ($T_A=25^\circ C$)	0.2	W
	Total Power Dissipation Single Operation ($T_A=70^\circ C$)	0.15	W
T_{STG}, T_J	Operating Junction Temperature & Storage Temperature	- 55 ~ 150	$^\circ C$
T_L	Maximum Lead Temperature for soldering purpose, 1/8 from Case for 10 seconds.	300	$^\circ C$

Thermal Characteristics

Symbol	Parameter	Value			Units
		Min.	Typ.	Max.	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	-	-	625	$^\circ C/W$

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Electrical Characteristics ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	60	-	-	V
$\Delta BV_{DSS} / \Delta T_J$	Breakdown Voltage Temperature coefficient	$I_D = 250\mu A$, referenced to $25\text{ }^\circ\text{C}$	-	48	-	mV/ $^\circ\text{C}$
I_{DSS}	Drain-Source Leakage Current	$V_{DS} = 60V, V_{GS} = 0V$ $V_{DS} = 60V, V_{GS} = 0V, T_J = 125\text{ }^\circ\text{C}$	-	-	1 500	μA
I_{GSS}	Gate-Source Leakage, Forward	$V_{GS} = 20V, V_{DS} = 0V$			100	nA
	Gate-Source Leakage, Reverse	$V_{GS} = -20V, V_{DS} = 0V$	-	-	-100	nA
On Characteristics						
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.0	-	2.5	V
$R_{DS(ON)}$	Static Drain-Source On-state Resistance	$V_{GS} = 10V, I_D = 500mA$ $V_{GS} = 4.5V, I_D = 50mA$	- -	1.55 2.10	7.5 7.5	Ω
Dynamic Characteristics						
C_{iss}	Input Capacitance	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$	-	20	25	pF
C_{oss}	Output Capacitance		-	11	14	
C_{rss}	Reverse Transfer Capacitance		-	3	4	
Dynamic Characteristics						
$t_{d(on)}$	Turn-on Delay Time	$V_{DD} = 30V, I_D = 115mA, R_G = 50\Omega$ $V_{GS} = 10V$ (Note 2,3)	-	4	18	ns
t_r	Rise Time		-	2.5	15	
$t_{d(off)}$	Turn-off Delay Time		-	18	46	
t_f	Fall Time		-	8	26	
Q_g	Total Gate Charge	$V_{DS} = 30V, V_{GS} = 4.5V, I_D = 115mA$ (Note 2,3)	-	0.5	0.65	nC
Q_{gs}	Gate-Source Charge		-	0.13	-	
Q_{gd}	Gate-Drain Charge(Miller Charge)		-	0.2	-	

Source-Drain Diode Ratings and Characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit.
I_S	Maximum Continuous Diode Forward Current		-	-	115	mA
V_{SD}	Diode Forward Voltage	$I_S = 115mA, V_{GS} = 0V$ (Note 2)	-	-	1.5	V

※ NOTES

1. Repeatability rating : pulse width limited by junction temperature
2. Pulse Test : Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$
3. Essentially independent of operating temperature.



Fig 1. On-State Characteristics

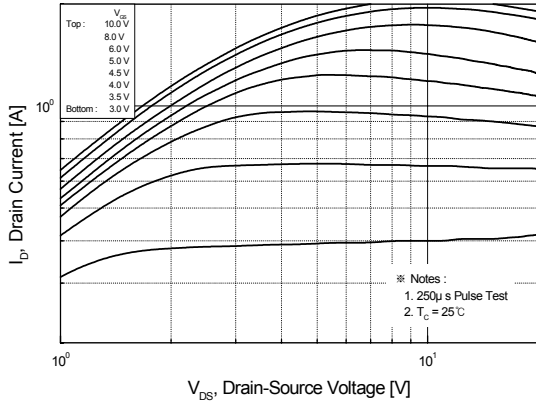


Fig 2. Transfer Characteristics

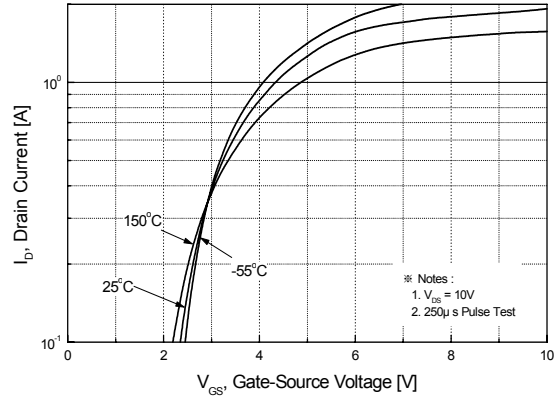


Fig 3. On Resistance Variation vs. Drain Current and Gate Voltage

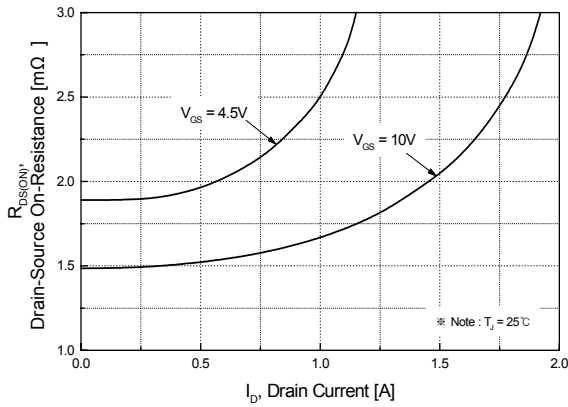


Fig 4. On State Current vs. Allowable Case Temperature

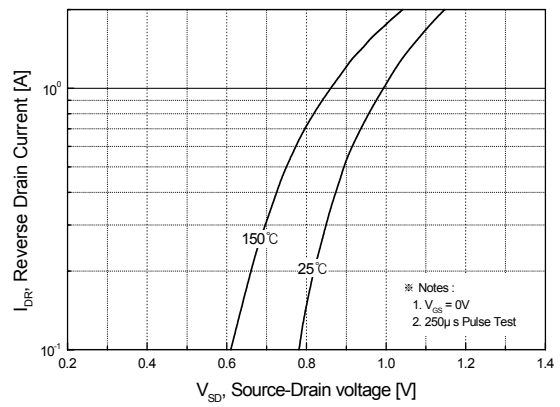


Fig 5. Capacitance Characteristics

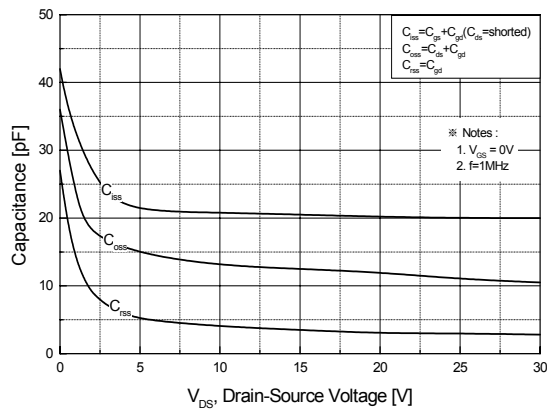
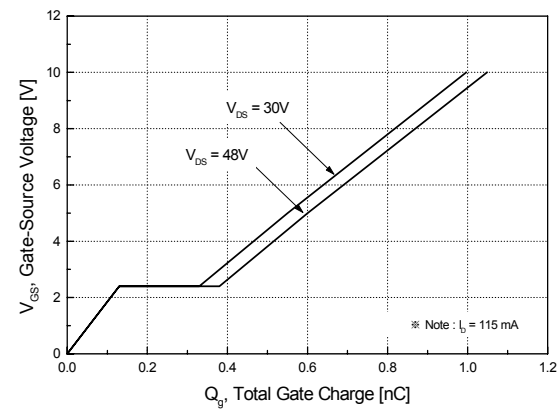


Fig 6. Gate Charge Characteristics



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Fig 7. Breakdown Voltage Variation vs. Junction Temperature

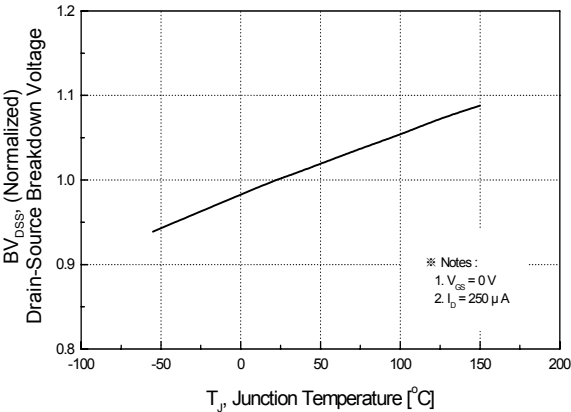


Fig 8. On-Resistance Variation vs. Junction Temperature

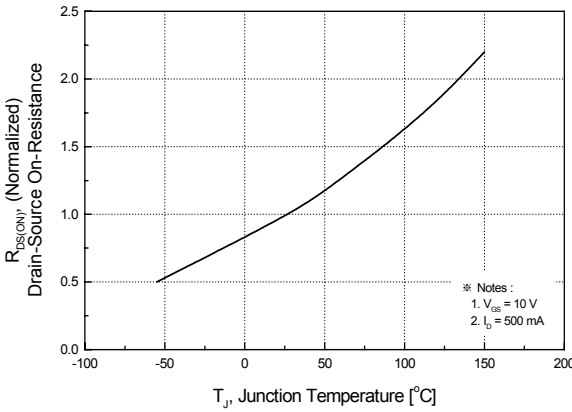


Fig. 9. Gate Charge Test Circuit & Waveforms

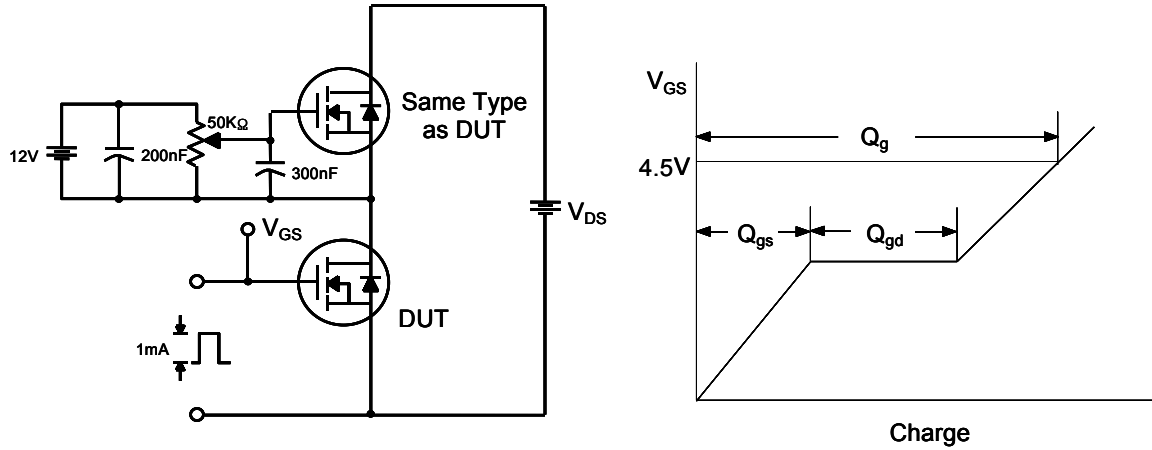
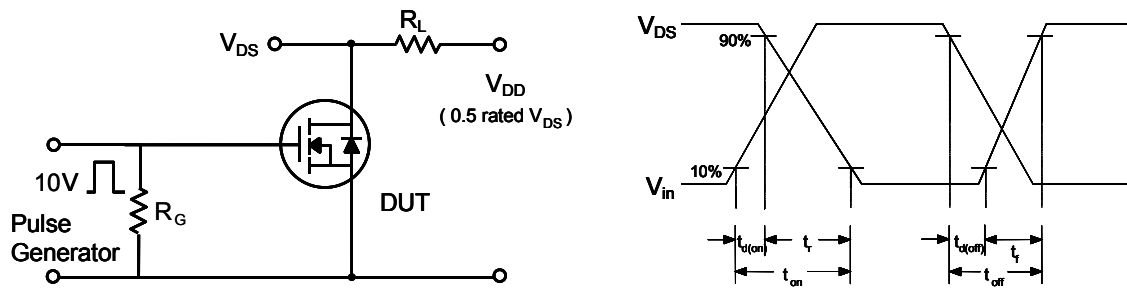


Fig. 10. Switching Time Test Circuit & Waveforms



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SOT-23 Package Dimension

Dim.	mm			Inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.900		1.100	0.035		0.043
B	0.900		1.000	0.035		0.039
C	0.000		0.100	0.000		0.004
D	0.300		0.500	0.012		0.020
E	0.080		0.150	0.003		0.006
F	2.800		3.000	0.110		0.118
G	1.200		1.400	0.047		0.055
H	2.250		2.550	0.089		0.100
I		0.950			0.037	
J	1.800		2.000	0.071		0.079
K		0.550			0.022	
L	0.300		0.500	0.012		0.020
\emptyset	0'		8'	0'		8'

